

1 2811 82
PATENT

Attorney's Docket No. 5308-156

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

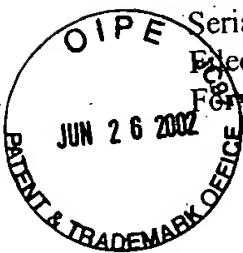
In re: Ryu et al.
Serial No.: 09/911,995

Group Art Unit: 2811
Confirmation No.: 5240

Filed: July 24, 2001

SILICON CARBIDE POWER METAL-OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS HAVING A SHORTING CHANNEL AND
METHODS OF FABRICATING SILICON CARBIDE METAL-OXIDE
SEMICONDUCTOR FIELD EFFECT TRANSISTORS HAVING A
SHORTING CHANNEL

Date: June 19, 2002



JUN 28 2002
RECEIVED
2800 MAIL ROOM

Commissioner for Patents
Washington, DC 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

Attached is a Supplemental Form PTO-1449 listing several documents cited in the International Search Report for the corresponding International Application Number PCT/US01/30715. Each document listed on the attached PTO-1449 was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Statement. A copy of each document, including the Search Report, is enclosed. It is requested that these documents be considered by the Examiner and officially made of record in accordance with the provisions of 37 C.F.R. § 1.97 and Section 609 of the MPEP. The Commissioner is hereby authorized to charge any additional fee, which may be required, or credit any refund, to our Deposit Account No. 50-0220.

Respectfully submitted,

Timothy J. O'Sullivan
Registration No. 35,632

Customer Number:



20792

PATENT TRADEMARK OFFICE

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, DC 20231, on June 19, 2002.

Traci A. Brown

Date of Signature: June 19, 2002